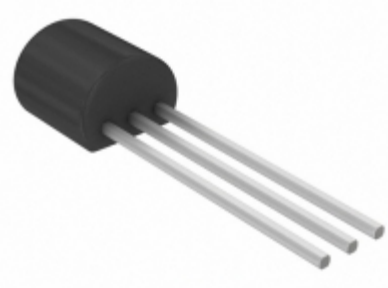











	<h2 style="color: red;">FJN4305RTA</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">FJN4305RTA</a>
	<b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> TRANS PREBIAS PNP 300MW TO92-3
	<b>Datenblätter:</b>  <a href="#">FJN4305RTA.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 1660 pcs Stock Available.
	<b>Liefern von:</b> Hong Kong
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	<a href="#">FJN4305RTA</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	TRANS PREBIAS PNP 300MW TO92-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-Bipolar</a>
Teilstatus	1660 pcs Stock
Hersteller Standard Vorlaufzeit	7 Weeks
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Through Hole
Leistung - max	300mW
Verpackung / Gehäuse	TO-226-3, TO-92-3 (TO-226AA) (Formed Leads)
Supplier Device-Gehäuse	TO-92-3
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	30 @ 5mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Cut Tape (CT)
Basisteilenummer	FJN4305
Widerstand - Basis (R1)	4.7 kOhms
Widerstand - Emitterbasis (R2)	10 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJN4305RTACT



















































FJN4305RTA ist neu im Original, Suche FJN4305RTA Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJN4305RTA AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJN4305RTA: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FJN4306RBU</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4305RBU</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4305RBU</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4305RTA</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>
 <p><b>FJN4306RTA</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4304RTA</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4304RBU</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>	 <p><b>FJN4304RTA</b> Fairchild/ON Semiconductor TRANS PREBIAS PNP 300MW TO92-3</p>

heiße Teile

Mehr

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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